OptaDOS: User Guide Version 1.0

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Introduction

1.1 Background

OPTADOS is a code for calculating optical, core-level excitation spectra along with full, partial and joint electronic density of states (DOS). The code was developed by merging the Lindos code of Andrew Morris and Chris Pickard at University College London with the optical properties code of Rebecca Nicholls and Jonathan Yates at Oxford University. OPTADOS is written in Fortran 95 and may be run in parallel using MPI. At present OPTADOS interfaces with CASTEP output files, although it is extendible to perform calculations on any set of band eigenvalues and their derivatives generated by any electronic structure code.

The code is freely available through the GPL licence with the request that the following citation (quoted in full) is required in any publication resulting from the use of OPTADOS.

Andrew J. Morris, R. J. Nicholls, C. J. Pickard and Jonathan R. Yates, The Optados code, Comp. Phys. Comm. (2011).

Further information and examples can be found at

www.optados.org

1.2 Features

OPTADOS generates optical, core-level excitation spectra along with full, partial and joint electronic DOS. The DOS, PDOS and JDOS take advantage of the linear and adaptive smearing schemes which are more accurate than standard Gaussian smearing since they exploit knowledge of the gradients of the bands at each k-point in the Brillouin zone. These DOS are the basis of the more advanced functionality of OPTADOS, the core and optical spectra.

Along with data text files OPTADOS also generates .agr files of results to be read by grace.

Getting Started

2.1 Installation

OPTADOS is usually obtained in a gzipped tarball, optados-X.X.tar.gz. Extract this (tar -xzf optados-X.X.tar.gz) in the desired directory. Inside the optados/directory are a number of sub directories, documents/, examples/. The code may be compiled using the Makefile in the optados/directory. The SYSTEM, BUILD, COMMS_ARCH and PREFIX flags must be set, either in the Makefile, or from the command line (for example make BUILD=fast).

2.1.1 SYSTEM

Choose which compiler to use to make Optados. The valid values are:

- g95 (default)
- gfortran
- ifort
- nag
- pathscale
- pgf90
- sun

2.1.2 BUILD

Choose the level of optimisations required when making OptaDOS. The valid values are:

- fast (default) All optimisations
- debug No optimisations, full debug information

2.1.3 COMMS_ARCH

Whether to compile for serial or parallel execution. The valid values are:

```
- serial (default)
```

- mpi

2.1.4 PREFIX

Choose where to place the OPTADOS binary. The default is the OPTADOS directory.

2.2 Usage

```
optados.x86_64 [seedname]
```

• seedname: If a seedname string is given the code will read its input from a file seedname.odi.

The default value is CASTEP.

Parameters

3.1 seedname.odi File

The OptaDOS input file seedname.odi has a flexible free-form structure.

The ordering of the keywords is not significant. Case is ignored (so smearing_width is the same as Smearing_Width). Characters after !, or # are treated as comments. Most keywords have a default value that is used unless the keyword is given in seedname.odi. Keywords may be set in any of the following ways

```
smearing_width = 0.4
smearing_width : 0.4
smearing_width 0.4
```

A logical keyword can be set to .true. using any of the following strings: T, true, .true..

3.2 General Parameters

3.2.1 character(len=20) :: task

Tells the code what to compute.

The valid options for this parameter are:

- dos (default)
- compare_dos
- compare_jdos
- jdos
- pdos
- optics
- core
- all

Several tasks can be specified *e.g.* to compute doi and jdos use task: dos jdos. However, the compare_dos and compare_jdos tasks can only be combined with each other, and no additional tasks. compare_dos and compare_jdos calculate the DOS and JDOS respectively using all broadening schemes. It is good practice to check the quality of the underlying DOS before other tasks are requested.

3.2.2 character(lex=50) :: broadening

Specified the scheme used to broaden a discrete sampling of the Brillouin Zone to a continuous spectral function.

The valid options for this parameter are:

- adaptive (default)
- fixed
- linear
- quad (not currently implemented)

3.2.3 integer :: iprint

This indicates the level of verbosity of the output from 1, the bare minimum: 2, with progress reports: to 3, which corresponds to full debugging output.

The default value is 1.

3.2.4 character(Len=20) :: energy_unit

The energy unit to be used for writing quantities in the output files.

The valid options for this parameter are:

- eV (default)
- Ry
- Ha

3.2.5 logical :: legacy_file_format

- TRUE Read CASTEP input compatible with versions < 6.0.
- FALSE (Default) Read CASTEP input compatible for use with CASTEP versions 6.0+ and generated with the castep spectral task.

3.2.6 real(kind=dp) :: adaptive_smearing

Set the relative smearing in the adaptive scheme.

Default value is 1.4

3.2.7 real(kind=dp) :: fixed_smearing

Smearing width for fixed broadening.

If spectral_scheme = fixed default value is 0.3eV.

3.2.8 real(kind=dp) :: scissor_op

Value of the scissor operator.

Default value is 0 eV (i.e. not used)

3.2.9 character(len=20 :: efermi

Choose which Fermi energy to use.

The valid options for this parameter are:

- optados (default) Optados recalculates the Fermi energy by performing a DOS calculation.
- file Take the value from the output of the ab-initio calculation.

- insulator Assume that the material is an insulator and counts filled bands to find the Fermi energy.
- <real number> User supplied value.

The default value is optados.

3.2.10 character(len=20) :: output_format

Format in which to output data.

The valid options for this parameter are:

- gnuplot
- grace (default)

3.2.11 logical :: finite_bin_correction

Force each Gaussian to be larger than a single energy bin. (Useful for adaptive smearing and semi-core states when numerical_intdos=TRUE).

Default value TRUE.

3.2.12 logical :: numerical_intdos

Calculate the integrated dos by numerical integration instead of semi-analytically. (Useful for comparison with Lindos.)

Default value FALSE.

3.2.13 logical :: hybrid_linear

Switch from linear broadening scheme to adaptive broadening when band gradient less than hybrid_linear_grad_tol. This allows for a good description of very flat bands such as defect and semi-core states. May also be used in conjunction with finite_bin_correction further improving the DOS and band energy

Default value FALSE.

3.2.14 real(kind=dp) :: hybrid_linear_grad_tol

Tolerance for switching from linear to adaptive broadening when using hybrid_linear option. The default value is $0.01 \mathrm{eV/\mathring{A}}$.

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3.2.15 character(len=50) :: devel_flag

Not a regular keyword. Its purpose is to allow a developer to pass a string into the code to be used inside a new routine as it is developed.

No default.

3.3 DOS Parameters

3.3.1 logical :: compute_band_energy

Compute the band energy by summing bands both using CASTEP's eigenvalue and OPTA-DOS's density of states.

Default value TRUE.

3.3.2 logical :: compute_band_gap

Compute the optical, thermal and avarage band gap.

Default value FALSE.

3.3.3 logical :: dos_per_volume

Present DOS per simulation cell volume.

Default value FALSE.

3.3.4 real(kind=dp) :: dos_min_energy

Lower energy range for DOS and related properties.

Default value is 5eV below the lowest eigenvalue in the bands file.

3.3.5 real(kind=dp) :: dos_max_energy

Upper energy range for DOS and related properties.

Default value is 5eV above the highest eigenvalue in the bands file.

3.3.6 real(kind=dp) :: dos_nbins

Instead of setting a Default value dos_spacing the total number of DOS bins may be given. (Useful for comparison with LinDOS.)

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3.3.7 real(kind=dp) :: dos_spacing

Resolution at which to compute the DOS and related properties. Default value is 0.1eV

3.3.8 logical :: set_efermi_zero

Shift energy scales so that the Fermi energy is at 0.

Default value FALSE.

3.4 JDOS Parameters

3.4.1 real(kind=dp) :: jdos_max_energy

Upper energy range for JDOS and related properties.

Default value is the difference between the valence band maximum (or Fermi level) and the highest eigenvalue in the bands file.

3.4.2 real(kind=dp) :: jdos_spacing

Resolution at which to compute the DOS and related properties. Default value is 0.01eV.

3.5 PDOS Parameters

3.5.1 character :: pdos

Defines which components to include in the pdos analysis:

- angular (decompose as s,p,d etc.)
- sites (decompose onto atomic sites, C, H etc.)
- species (decompose onto atomic species C1, H1, H2 etc.)
- species_ang (decompose onto angular momentum channels and species C1s, C1p etc.)
- C:H (decompose onto Carbon and Hydrogen sites)
- C1:C3:C4-C8 (decompose onto atoms C1, C2 and C4,C5,C6,C7,C8)
- Sil[s;d] (decompose onto 's' and 'd' channels for atom Sil)
- sum:C1:C3:C4-C8 (decompose onto atoms C1, C2 and C4,C5,C6,C7,C8 and combine into the single projection)

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3.6 Optics Parameters

3.6.1 character(len=20) :: optics_geom

Specifies the geometry for the optics calculation. Possible options:

- polycrystalline (Isotropic average)
- polarized
- unpolarized
- tensor (Full dielectric tensor)

The default is polycrystalline.

3.6.2 real(kind=dp) :: optics_qdir(3)

Direction of polarisation. Must be specified if optics_geom :polarized or optics_geom : unpolarized. No default

3.6.3 logical :: optics_intraband

Calculate the intraband contribution to the dielectric function. (Important for metals.) The default is FALSE.

3.6.4 real(kind=dp) :: optics_drude_broadening

Value of broadening included in the Drude term expressed in s^{-1} . The default value is 1E-14.

3.7 Core-hole Parameters

3.7.1 character(len=20) :: core_geom

Specifies the geometry for the core-spectra calculation. Possible options:

- polycrystalline (Isotropic average)
- polarized

The default is polycrystalline.

3.7.2 character(len=20) :: core_type

Determines if we want absorption (transition from core to conduction ELNES / XANES) or emission (transition from valence to core XAS). It is also possible to plot both.

- absorption (default)
- emission
- all

3.7.3 real(kind=dp) :: core_qdir(3)

Direction of polarisation. Must be specified if core_geom :polarized. No default

3.7.4 logical :: core_LAI_broadening

Include life-time and instrumentation broadening. The default is FALSE.

3.7.5 real(kind=dp) :: LAI_gaussian_width

FWHM of Gaussian function used to broaden spectrum.

The default value, if core_LAI_broadening: true, is 0 (i.e. no Gaussian used).

3.7.6 real(kind=dp) :: LAI_lorentzian_width

FWHM of fixed Lorentzian function used to broaden spectrum.

The default value, if core_LAI_broadening: true, is 0 (i.e. no fixed Lorentzian used).

3.7.7 real(kind=dp) :: LAI_lorentzian_scale

Variation of Lorentzian function with energy i.e. the width of the Lorentzian is energy x core_lorentzian_scale. If set to zero, no energy dependent broadening is included. If core_lorentzian_scale and core_lorentzian_width are both specified, the total width of the Lorentzian used will be core_lorentzian_width + (energy x core_lorentzian_scale).

The default value, if core_LAI_broadening: true, is 0.1.

3.7.8 real(kind=dp) :: LAI_lorentzian_offset

Energy (in eV) above the edge onset that the energy dependent broadening starts. The default value, if core_LAI_broadening :true, is 0.

Examples

Each example in the examples/ directory contains example CASTEP input files and a sample OPTADOS input file. To keep the OPTADOS distribution light CASTEP output files for the examples have not been provided. You need to run CASTEP on the CASTEP input files before running OPTADOS on the examples.

4.1 Density of States

- Outline: This is a simple example of using OptaDOS for calculating electronic density of states of crystalline silicon in a 2 atom cell.
- Input Files:
 - examples/Si2_DOS/Si2_dos.cell The CASTEP cell file containing information about the simulation cell.
 - examples/Si2_DOS/Si2_dos.param The CASTEP param file containing information about the parameters for the SCF and spectral calculations.
 - examples/Si2_DOS/Si2_dos.odi The OPTADOS input file, containing the parameters necessary to run OPTADOS.
- Perform a CASTEP calculation on the bulk silicon using the Si2_dos.cell and Si2_dos.param input files.

\$ castep Si2

This should take a couple of seconds to run. More help can be found in the tutorials on the CASTEP website www.castep.org.

- 2. Perform an OptaDOS calculation. Add LEGACY_FILE_FORMAT: true in the Si2_DOS.odi input file, if the CASTEP version you are using is before 6.0. Then execute:
 - \$ optados.<SYSTEM>.<BUILD>.<COMMS_ARCH>.x86_64 Si2

This generates 3 files:

- Si2.odo OptaDOS general output file.
- Si2.adaptive.dat The adaptive broadened DOS raw output data.
- Si2.adaptive.agr The adaptive broadened DOS in a file suitable to be plotted by xmgrace.
- 3. Open the Si2.odo file in a text editor (e.g. vi or emacs). OPTADOS has performed a Density of States calculation.

It has used the integrated DOS to work out the Fermi level, and has suggested the error in the integration by indicating the number of electrons at the Fermi level. Since we had 4 up electrons and 4 down in the input file this analysis seems satisfactory.

Since we had efermi_choice: optados, OPTADOS sets the internal value of the Fermi level to the one it has derived from the DOS. This is important for subsequent calculations. Other valid options are file, where OPTADOS uses the value calculated by the electronic structure code that generated the eigenvalues; insulator, where OPTADOS uses a value calculated from assuming the system is non-metallic; or a value set by the user.

OPTADOS now performs some analysis of the DOS at the Fermi level,

```
+----- DOS at Fermi Energy Analysis ------
| Fermi energy used : 5.4109 eV |
| From Adaptive broadening |
| Spin Component : 1 DOS at Fermi Energy : 0.0011 eln/cell | <- DEA |
| Spin Component : 2 DOS at Fermi Energy : 0.0011 eln/cell | <- DEA |
```

From this we may assume that there is a band gap.

Importantly, then OPTADOS calculates the band energy from the DOS is has calculated.

As the quality of the OptaDOS calculation is increased these two values should converge to the same answer.

Finally OptaDOS shifts the Fermi level to 0 eV, for the output files.

4. The DOS is outputted to Si2.adaptive.dat. This contains 5 columns as described in the header of the file:

```
#
#
            OptaDOS output file
#
#
   Density of States using adaptive broadening
 Generated on 12 Feb 2012 at 16:50:37
#
 Column
          Data
#
#
   1
        Energy (eV)
   2
         Up-spin DOS (electrons per eV)
   3
         Down-spin DOS (electrons per eV)
         Up-spin Integrated DOS (electrons)
#
   4
#
   5
         Down-spin Integrated DOS (electrons)
```

This file can be plotted by your favourite graph-plotting software. However, OPTADOS has made things easy and generated a Si2.adaptive.agr file which is directly plottable using xmgrace as shown in Fig. 4.1.

- \$ xmgrace Si2.adaptive.agr.
- 5. We now try again with a better sampling of the DOS, by setting DOS_SPACING: 0.001 and also analyse the band gap, by setting COMPUTE_BAND_GAP: true. You can remove all of the OPTADOS output files by using ./tools/optados_clean in your working directory. If you have a parallel version of OPTADOS compiled, now might be the time to try it out, if not, the serial version will be fine, but just take a bit longer. You can set IPRINT: 2 to see a progress report in Si2.odo. In parallel:
 - \$ mpirun -np <nprocs> optados.SYSTEM.BUILD.COMMS_ARCH.x86_64 Si2 but your MPI implementation may be different.
- 6. In Si2.odo we now have a new section analysing the band gap in various ways.

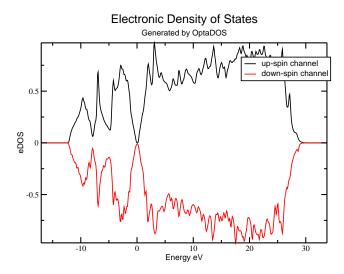


Figure 4.1: Density of States of Silicon generated by adaptive broadening and a very coarse energy sampling of 0.1 eV.

Thermal Bandgap : 0.6676272107 eV Between VBM kpoint : 0.05000 0.05000 0.05000 and CBM kpoint: -0.45000 -0.05000 -0.45000 ==> Indirect Gap	<- TBg
Optical Bandgap	
Spin: 1: 2.5542517447 eV	<- OBg
Spin: 2: 2.5542463024 eV	<- OBg
Number of kpoints with this gap	1
Spin: 1: 1	1
Spin : 2 : 1	1
Average Bandgap	+
Spin : 1 : 3.8121372691 eV	<- ABg
Spin : 2 : 3.8121342659 eV	<- ABg
Weighted Average : 3.8121357675 eV	<- wAB

OPTADOS is very careful in its band gap analysis. It uses the bare eigenvalues (unbroadened) and works out the nature and size of the thermal gap, optical gap and the average gap over all of the Brillouin zone. In cases of multi-valleyed semiconductors OPTADOS will report the number of conduction band minima or valence band maxima with identical energies, but will not report the nature of the gap.

Increasing the number of integration points has improved the band energy of the adaptive smearing:

Band energy (Adaptive broadening): 1.3623 eV | <- BEA

7. Now set TASK: compare_dos and re-run OPTADOS. OPTADOS will calculate DOS using all the broadening methods, this is good practice to see whether the broadening widths are appropriate before more advanced tasks are carried out, such as Joint-DOS, core and optical calculations.

Plotting the linear broadened DOS over the adaptive we see that the default adaptive broadening is appropriate,

```
xmgrace Si2.adaptive.agr -nxy Si2.linear.dat
```

Linear broadening, although a massive improvement over fixed broadening, sometimes appears noisy if used with very low numbers of k-points. Linear and adaptive DOS should be compared and ADAPTIVE_SMEARING may be tuned by eye until the adaptive DOS contains the features of the linear DOS, but with less noise. Adding a random shift to a k-point mesh can greatly increase the quality of the DOS, especially if the k-point set contained the Γ -point. It is generally pays of in computational time to have a coarse mesh at low symmetry points, than a fine mesh centred on high symmetry points.

Both fixed and adaptive broadening can fail to plot the sharpest features, such as semi-core states, if the bin widths are too broad. These sharp features may be forced to be present using the narrowest Gaussian still reproducible by the chosen bin widths by setting FINITE_BASIS_SET: true.

Linear broadening may also be improved by using HYBRID_LINEAR: true. Van Hove singularities and other sharp features are now described at the adaptive broadening level if the bands are flatter than HYBRID_LINEAR_GRAD_TOL. Hybrid linear may also take advantage of the finite bin correction if required.

8. Compare the fixed and adaptive DOS and see the advantage of adaptive broadening over standard Gaussian smearing.

4.2 Projected Density of States

We assume the reader is familiar with the previous section on Density of States calculations and is now familiar with choosing broadening widths, and running OPTADOS.

- Outline: This is a simple example of using OptaDOS for calculating electronic density of states of 2 atoms of crystalline silicon projected onto LCAO basis states.
- Input Files:
 - examples/Si2_PDOS/Si2_dos.cell The CASTEP cell file containing information about the simulation cell.
 - examples/Si2_PDOS/Si2_dos.param The CASTEP param file containing information about the parameters for the SCF and spectral calculations.
 - examples/Si2_PDOS/Si2_dos.odi The OPTADOS input file, containing the parameters necessary to run OPTADOS.

- 1. Choose a broadening scheme for the projected-DOS calculation and test using TASK: compare_dos as explained in the previous example. Checking that the DOS_SPACING is sufficiently fine for the band energies to match.
- 2. Once the DOS looks suitable, switch to TASK: pdos. We choose to decompose the DOS into angular momentum channels (PDOS: angular) and as in the previous example we choose to recalculate the Fermi level using the calculated DOS, rather than use the Fermi level suggested by CASTEP.
- 3. Execute Optados.
- 4. The output can be found in Si2.pdos.dat.

```
#
#
            OptaDOS
                      output
#
  Generated on 13 Feb 2012 at 10:15:10
Partial Density of States -- Projectors
#| Projector:
          1 contains:
        Atom
                 AngM Channel
#|
       Si 1
                      s
                      S
#| Projector:
          2 contains:
              AngM Channel
        Atom
#|
       Si 1
                      р
       Si
#| Projector:
          3 contains:
            AngM Channel
        Atom
#|
       Si
                      d
          1
       Si
                      d
#| Projector:
          4 contains:
        Atom
            AngM Channel
#|
       Si
          1
                      f
#|
                      f
       Si
```

The header shows that there are four projectors described below. The first containing the s-channels of both silicon atoms, the second the p-channels etc.

5. The output is easily plotted using xmgrace:

```
xmgrace -nxy Si2.pdos.dat
```

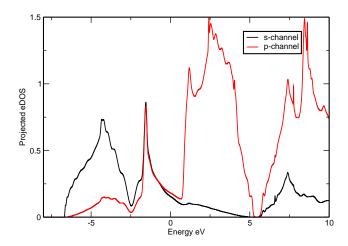


Figure 4.2: Density of States of Silicon generated by adaptive broadening projected onto LCAO momentum states.

- 6. Setting DOS_SPACING: 0.001 gives a high quality plot, as shown in Fig 4.2
- 7. Other things to try are:
 - PDOS: Si1;Si2(s) Output the PDOS on Si atom 1 and the PDOS on the s-channel of Si atom 2. (Resulting in two projectors)
 - PDOS: sum:Si1-2(s) Output the sum of the s-channels on the two Si atoms. (Resulting in one projector)
 - PDOS: Si1(p) Output the p-channel on Si atom 1. (Resulting in one projector)

4.3 JDOS

See examples/Si2_JDOS/. This is a simple example of using OPTADOS for calculating joint electronic density of states. This is a simple example of using OPTADOS for calculating joint electronic density of states. We choose to recalculate the Fermi level using the calculated DOS, rather than use the Fermi level suggested by CASTEP. If TASK: compare_jdos is used instead, OPTADOS will calculate the JDOS using all the broadening methods, this is good practice to see whether the broadening widths are appropriate before more advanced tasks are carried out. The JDOS is outputted to Si2.jadaptive.dat. A file suitable for plotting using xmgrace is written to Si2.jadaptive.agr.

4.4 CORE

See examples/diamond_CORE/. This is a simple example of using OPTADOS for calculating core level spectra.

4.5 OPTICS

See examples/Al_OPTICS/. This is a simple example of using OPTADOS for calculating optical properties.

Frequently Asked Questions

5.1 OptaDOS crashes complaining that it can't read the seed.bands or seed.cst_ome file.

Which version of CASTEP are you using? See Sect. 3.2.5.

5.2 I'd like OptaDOS to do X as well

Contact the developers we're always interested in discussing new functionality.

5.3 I'd like to help, what can I do?

Contact the developers, there's always more functionality that we'd like to add to the code.

5.4 I think I've found a bug: what should I do?

- Check and re-check that it is a bug.
- Check the output of the electronic structure code.
- Check that you're using the latest version of OptaDOS.
- Email the developers the input and output files with iprint: 3 and as much information about the problem as possible.